With a laser rod having high-reflectivity mirrors on both ends, threshold was reached at a rod temperature of 3.5 °C at 250 mA/diode.

The dotted portion of the curve in Fig. 3 is an extrapolation, based on Fig. 2, to a rod temperature of 20 °C. In these experiments we were limited to an array of 19 diodes by the dimensions of the case in which the diodes were mounted rather than the size of the emitting elements themselves. With a more compact diode package the number of diodes could be increased by a factor of 3-4.

Using Fig. 3 to extrapolate, a rod at 20 °C pumped by 60 diodes would be 2.2 times above threshold and when pumped by 80 diodes would be 2.9 times above threshold.

The optical pump power would be 3 to 4 times higher than in the present experiments and the laser rod would undoubtedly have to be more efficiently heat sunk. This could be readily accomplished by coating half the outer surface of the rod with gold and thermally bonding it into a channel in the heat sink. This would represent a considerable improvement in the conductivity between the rod and heat sink, and no heating problem is anticipated at these higher power levels. Therefore, we conclude that a cw diode pumped YAG: Nd laser operating at room temperature (20 °C) with a power output = 50 mW can be built with presently available 4% efficient GaAs1-xPx diodes.

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PARAMETER DEPENDENCE OF ACoustoelectric AMPLIFICATION IN InSb†

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On the basis of a hydrodynamical theory of the acoustoelectric interaction (Fleming-Rowe) reported earlier which included electron inertial terms it is found that for sufficiently large electron drift velocities sharp high-gain peaks occur. Furthermore the peak values of gain achieved greatly exceed the maximum gain of the corresponding theory of Steele. Excellent agreement with recently reported experimental measurements of microwave acoustic gain in InSb is obtained. It is also noted that for large applied fields, empirical field factors are required to give agreement with experiment.

Recently it has been concluded by several investigators1-3 that detailed microscopic theories are required to adequately account for microwave acoustoelectric effects in InSb. It has been shown by the authors4 that, when electron inertial terms are retained, a hydrodynamical theory of the acoustoelectric interaction gives valuable insight into the interaction process. When this theory is modified to include empirical field factors excellent agreement with experimental measurements of microwave acoustic gain1-5 is obtained.

The derivation and notation of the hydrodynamical theory developed by the authors followed that of other related work.6-8 Retaining electron inertial terms, we find that the acoustoelectric growth rate, occurring in the presence of a transverse magnetic field $B_z$, is

\[ \alpha = -\kappa \frac{\omega_0^2}{2\nu_s} \gamma \left( \frac{\omega'}{\omega' + \omega} \right) \]

(1)

where $\kappa$ is the electromechanical coupling constant, $\nu_s$ is the sound wave velocity, $\gamma = 1 - u_v/v_s$, where $u_v$ is the electron drift velocity, $W' = \omega_0^2/\omega + \omega/\omega_0$, $\omega' = \omega_0/\nu'$ is the effective dielectric relaxation frequency, $\omega'_R = \omega_0/\nu'_R$ is the effective diffusion frequency, $\omega'_R = \omega_0/\nu'_R$, $\nu$ is the electron relaxation frequency, $\nu_R$ is the electron thermal velocity, $\nu'_R = 1 + b'^2$, $b'^2 = b^2/(1 + \omega_0^2)$, where $b$ is the dimensionless $\mu B_z$ product, and $\omega_v = \omega_0/\nu$ is the parameter which...
includes the effect of electron inertial terms. When inertial terms are neglected, \( \omega_p - 0 \), (1) reduces to the corresponding result of Steele.\(^6\) When the magnetic field is zero, \( b = 0 \), (1) reduces to the result of Kino and Route\(^7\) and when both inertial terms and the magnetic field effects are neglected, \( \omega_p - 0 \) and \( b = 0 \), (1) reduces to the result of White.\(^8\)

Abe and Mikoshiba\(^9\) have previously considered the case \( \omega_p \neq 0 \) and \( b \neq 0 \); however, their results are in error. When \( b = 0 \), their hydrodynamical theory does not reduce to the results of Kino and Route.\(^7\) The discrepancy arises from the specialized magnetohydrodynamic expression [Eq. (1) of Ref. 9] which they use for the equation of momentum conservation. This equation is given in terms of current rather than electron velocity and is incorrectly introduced the space-charge term \( Q \).\(^9\) No=6.1X10^14 cm^-3 (solid curves denote theoretical results).

Acoustic gain is calculated from (1) using the relation, gain = 10 \log_{10} \left[ \exp(2\alpha) \right] = 8.68 \alpha (\text{dB/cm}).\(^9\)

The results of this calculation are shown in Fig. 1, where it is seen that no significant error is present in the theory of Abe and Mikoshiba\(^9\) for electron drift velocities less than approximately \( 3 \times 10^4 \) cm/sec. However, at large drift velocities, the theory of Abe and Mikoshiba noticeably diverges from the theory of the present paper as a result of their error. The locations of the sharply peaked maximum gain values which exist for \( \nu_0 > \nu_T \) can be determined directly from (1). They occur when the condition \( W' = 0 \) is satisfied and this condition is given, in good approximation, by

\[
\gamma^2 = (\nu_0^2/\nu_T^2)[1 + (\omega_p/\omega)^2 (1 + \omega_3^2)], \tag{2}
\]

where \( \omega_3 = (\omega_p/\omega)^{1/2} = 2\phi_0 \) and \( \omega_3^2 = b_T^2 = b_T^2 = b_T^2 \). Physically, it can be shown that (2) corresponds to cancellation of the diffusion term by the electron inertial term in the equation of momentum conservation. From (1) and (2) maximum gain is given, in good approximation, by

\[
(gain)_{\text{max}} = 8.68 \kappa^2 \frac{\omega_0}{2\nu_T} \frac{[1 + (\omega_p/\omega)^2 (1 + \omega_T^2)]^{1/2}}{[1 + (\omega_p/\omega)^2 (1 + \omega_T^2)]} \tag{3}
\]

At the frequency \( f = f_0 = 1.45 \) GHz, substitution of the parameters of Fig. 1 into (2) and (3) yields (gain)\(_{\text{max}} = 623 \) dB/cm which occurs at \( \nu_0 = 5.1 \times 10^4 \) cm/sec for \( b = 0 \). This value of maximum gain is 14.7 times greater than the corresponding maximum gain given by Steele’s theory,\(^6\) however, it can only occur for \( \nu_0 > \nu_T \) and \( b \approx 0 \). Under these conditions, electron effects and microscopic resonance effects must be considered. Notwithstanding, extensive numerical calculations\(^4\) have shown that at more reasonable drift velocities (\( \nu_0 \approx 0.8 \nu_T \)), the essential features of the corresponding microscopic theories\(^1\) are retained in the present hydrodynamical theory. In particular, analysis of the present theory indicates that the Mode 1 acoustic domain formation (which occurs for \( \nu_0 > 0.4 \nu_T \) and \( b \approx 0 \)) does not critically depend on microscopic resonance effects but rather, it arises from the same physical mechanism which gives rise to the sharp gain peaks of Fig. 1, namely, a drift-enhanced quenching of electron diffusion effects.

In Fig. 2 the theoretical acoustic characteristics are calculated from (1) and are compared to the experimental results of Route and Kino.\(^1\) The
agreement is excellent except for the zero magnetic field curve. Although the microscopic theory gives better agreement for the zero magnetic field curve, the hydrodynamical theory of the present paper gives as good, if not better, agreement for the remaining \((B_z \neq 0)\) acoustic gain curves.

Under other conditions, field-dependent effects such as electron mobility saturation and geometrical magnetoresistance are important. An empirical relation for the mobility saturation is obtained by a least-squares fit to the \(I-V\) characteristic data. The \(I-V\) curve, the hydrodynamical theory of the present theory of Fleming and Rowe, where \(b\) and \(\alpha\) are the length and width of the specimen, and \(M_1(b) = R_0(b)/R_0(0)\) is the magneto-resistance ratio. The values \(\delta_1 = 0.8526, \delta_2 = 0.0915,\) and \(\delta_3 = 0.2389\) are obtained.

The empirical field factors given by (4) and (5) are incorporated into (1) in the following manner. Specifying an electron drift velocity \(u_0\), the applied current and applied electric field are determined by

\[
J_0 = Q_6 N u_0 \quad \text{and} \quad E_0 = (u_0/\mu) \cdot M_1(b) \cdot F(J_0),
\]

where \(\mu_0\) is the low-field electron mobility. Assuming that the field-dependent electron mobility varies as \(\mu = \mu_0/F(J_0)\), the relaxation parameters in (1) become \(\omega_0 - \omega F(J_0), \omega_0 - \omega F(J_0), \nu - \nu \cdot F(J_0),\) and \(b - b/F(J_0)\). The importance of these empirical relations is illustrated in Fig. 3(a). Experimental acoustic gain values are taken from the work of Hayakawa and Kikuchi. The curves labeled \(G_{A-M}\) and \(G_{F-R}\) are, respectively, the theoretical results of the theory of Abe and Mikoshiba and the present theory of Fleming and Rowe, where (in both cases) no empirical effects are included and the electric field is taken as \(E_0 = u_0/\mu_0\). Only the effect of magnetoresistance has been included in the curve \(G_{F-R}(M_1)\) wherein \(E_0 = (u_0/\mu_0) \cdot M_1(b)\).

Finally, all empirical factors are included in the curve \(G_{F-R}(M_1, \mu(E))\), wherein the effects of mo-
bility saturation are now included in the gain calculation and the electric field is given by (6). It is apparent that the empirical field factors must be included in order to obtain good agreement between experiment and theory.

In Fig. 3(b) the complete set of theoretical acoustic gain characteristics, including all the empirical field factors and using (1), are compared to the experimental results. Over-all good agreement is obtained. Deviations from the experimental results are attributed to discrepancies between the assumed empirical field factors of (6) and the actual field factors of the experiment.

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TYPE CONVERSION AND p-n JUNCTION FORMATION IN LITHIUM-ION-IMPLANTED ZnSe

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High-conductivity n-type ZnSe implanted with Li ions gives evidence of type conversion when tested by thermal probe measurements. Photovoltaic effect, current rectification, and low-voltage electroluminescence were observed in diodes fabricated from implanted material.

We have observed p-type conduction in Li-ion-implanted n-type ZnSe single crystals and formed p-n junctions. Type conversion and p-n junction formation by ion implantation have been recently produced in other similar II-VI compounds, n-CdS, 1-3 n-CdTe, 4 and p-ZnTe, 5 but this is the first report of successful type conversion produced by ion implantation in high-conductivity n-ZnSe.

ZnSe crystals, as grown, usually exhibit high-resistivity n-type conductivity. High resistivity is thought to arise from stoichiometric deficiency; possibly due to Zn vacancies produced during crystal growth. Undoped crystals of ZnSe grown from the melt by Eagle-Picher Co. were used in this experiment. As received, these crystals showed high resistivity in the range \(10^9-10^{10}\ \Omega\cdot\text{cm}\) at room temperature. By firing in molten Zn for 24 h at 900 °C, we obtained low-resistivity crystals in the range of 0.1-10 Ω-cm. A crystal having a resistivity of 3 Ω-cm had, for example, a room-temperature electron mobility of 480 \(\text{cm}^2/\text{V sec}\) and a carrier concentration of \(4\times10^{15}\ \text{cm}^{-3}\). Typical sample dimensions used for implantation were \(13\times7\times1\) mm. Wafers were cleaved and \(\langle 110 \rangle\) oriented. Following heat treatment in molten Zn, the implantation surface was optically finished and chemically etched for several seconds in concentrated boiling NaOH.

All implantations 6 were carried out at room temperature. Li ions were supplied from the source material of beta-eucryptite 7 pasted on the tungsten filament in the ion source. The mass analyzer was